

规格书编号

SPEC NO:

产品规格书 SPECIFICATION

CUSTOMER 客户:_						
PRODUCT 产品:_	SAW FILTER					
MODEL NO 型 号:_	HDBF14001A24					
PREPARED 编 制: _		CHECKED 审 核:	Houshihong			
APPROVED 批准:	CHARLES	D A T E 日 期:	2007-01-25			
客户确认 CUSTOMER RECEIVED:						
审核 CHECKED	D 批准 APPROVED		日期 DATE			

无锡市好达电子有限公司 Shoulder Electronics Limited



HDBF14001A24

更改历史记录 History Record

更改日期 Date	规格书编号 Spec No	产品型号 Part No	客户产品型号 Customer No	更改内容描述 Modify Content	备注 Remark



1. SCOPE

This specification shall cover the characteristics of SAW filter BF14001A24

2. ELECTRICAL SPECIFICATION

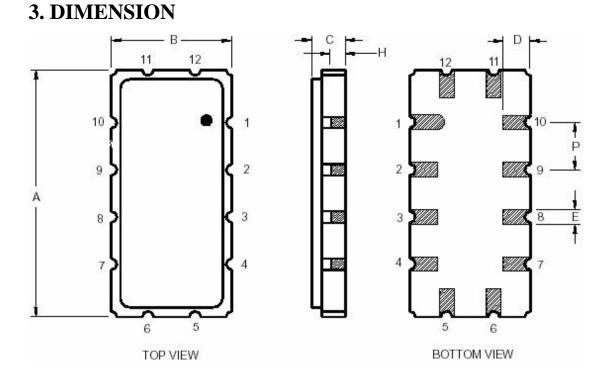
DC Voltage VDC	10V
AC Voltage Vpp	10V50Hz/60Hz
Operation temperature	-10°C to +60°C
Storage temperature	-40°C to +85°C
RF Power Dissipation	0dBm

Electronic Characteristics

Fo = 140.0 MHz

Terminating source impedance: 50 ohm and matching network Terminating load impedance: 50 ohm and matching network

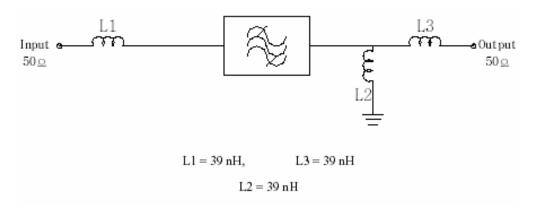
		Minimum	Typical	Maximum
Center Frequency	MHz	-	140.0	-
Insertion Loss	dB	-	21.0	25.5
1dB Bandwidth	MHz	-	1.26	-
3dB Bandwidth	MHz	1.3	1.45	-
40dB Bandwidth	MHz	-	2.15	2.3
Amplitude Ripple (Fo +/- 0.55 MHz)	dB	-	0.5	1.0
Group Delay Variation (Fo +/- 0.55 MHz)	nsec	-	200	300
Absolute Delay	usec	-	3.72	-
Ultimate Rejection	dB	50	55	
Temperature Coefficient of Frequency	ppm/°C		-0.03	



Pin Configuration			
11	Input		
5	Output		
Other	Ground		

Dimension	mm			
	min	typ	max	
A	13.1	13.3	13.5	
В	6.3	6.5	6.7	
С	1.21	1.36	1.51	
D		1.5		
Е		0.8		
Н	0.72	0.76	0.80	
P		2.54		

4.TEST CIRCUIT





5. ENVIRONMENTAL CHARACTERISTICS

5-1 High temperature exposure

Subject the device to $+85^{\circ}$ C for 16 hours. Then release the filter into the room conditions for 24 hours prior to the measurement. It shall fulfill the specifications in table 1.

5-2 Low temperature exposure

Subject the device to -20° C for 16 hours. Then release the device into the room conditions for 24 hours prior to the measurement. It shall fulfill the specifications in table 1.

5-3 Temperature cycling

Subject the device to a low temperature of -40° C for 30 minutes. Following by a high temperature of $+80^{\circ}$ C for 30 Minutes. Then release the device into the room conditions for 24 hours prior to the measurement. It shall meet the specifications in table 1.

5-4 Resistance to solder heat

Dip the device terminals no closer than 1.5mm into the solder bath at 260° C $\pm 10^{\circ}$ C for 10 ± 1 sec. Then release the device into the room conditions for 4 hours. The device shall meet the specifications in table 1.

5-5 Solderability

Subject the device terminals into the solder bath at 245° C $\pm 5^{\circ}$ C for 5s, More than 95% area of the terminals must be covered with new solder. It shall meet the specifications in table 1.

5-6 Mechanical shock

Drop the device randomly onto the concrete floor from the height of 1m 3 times. the device shall fulfill the specifications in table 1.

5-7 Vibration

Subject the device to the vibration for 1 hour each in x,y and z axes with the amplitude of 1.5 mm at 10 to 55 Hz. The device shall fulfill the specifications in table 1.

5-8 Lead fatigue

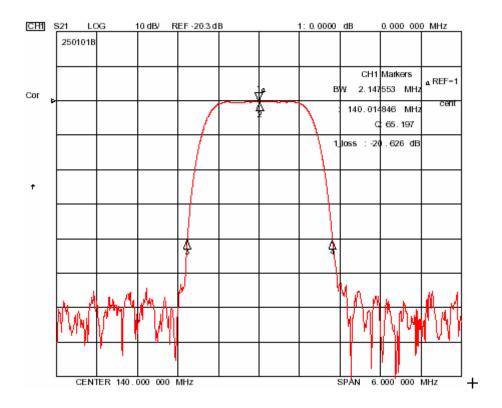
5-8-1 Pulling test

Weight along with the direction of lead without an shock 1kg. The device shall satisfy all the initial Characteristics.

5-8-2 Bending test

Lead shall be subject to withstand against 90° C bending with 450g weight in the direction of thickness. This operation shall be done toward both direction. The device shall show no evidence of damage and shall satisfy all the initial electrical characteristics.

6.Typical frequency response



7. REMARK

7.1 Static voltage

Static voltage between signal load & ground may cause deterioration &destruction of the component. Please avoid static voltage.

7.2 Ultrasonic cleaning

Ultrasonic vibration may cause deterioration & destruction of the component. Please avoid ultrasonic cleaning

7.3 Soldering

Only leads of component may be soldered. Please avoid soldering another part of component.